

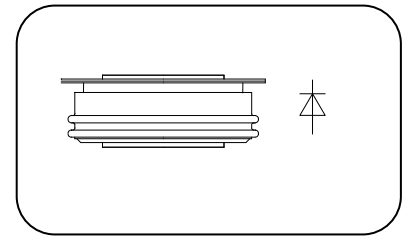
Features

- Low forward voltage drop
- Soft recovery
- Hermetic metal cases with ceramic insulators

Typical Applications

- Inverters and choppers
- Motor control
- Snubber and free-wheeling diodes

$I_{F(AV)}$ **710A**
 V_{RRM} **1100~2000V**
 t_{rr} **3.0 μ s**



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT	
				Min	Type	Max		
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Double side cooled,	T _c =55°C			930	A	
			T _c =85°C			710		
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RSM} = V _{RRM} +100V	150	1100		2000	V	
I _{RRM}	Repetitive peak current	V _{RM} = V _{RRM}	150			30	mA	
I _{FSM}	Surge forward current	10ms half sine wave	150			9	kA	
I ² t	I ² T for fusing coordination	V _R =0.6V _{RRM}				405	A ² s*10 ³	
V _{FO}	Threshold voltage		150			1.30	V	
r _F	Forward slop resistance					0.42	mΩ	
V _{FM}	Peak on-state voltage	I _{TM} =1200A, F=7.0kN	150			1.80	V	
I _{rm}	Reverse recovery current	I _{TM} =1000A, tp=1000μs, -di/dt=60A/μs, V _R =50V	150		42		A	
t _{rr}	Reverse recovery time				3.0			μs
Q _{rr}	Recovery charge				63	90		μC
R _{th(j-c)}	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 7.0kN				0.045	°C/W	
R _{th(c-h)}	Thermal resistance case to heat sink					0.010		
F _m	Mounting force			5.3		10	kN	
T _{stg}	Stored temperature			-40		160	°C	
W _i	Weight				80		g	
Outline	ZT25aT							

Outline:

